

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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Not recommended  
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# MOS FIELD EFFECT TRANSISTOR

# $\mu$ PA2550

## DUAL P-CHANNEL MOSFET FOR SWITCHING

### DESCRIPTION

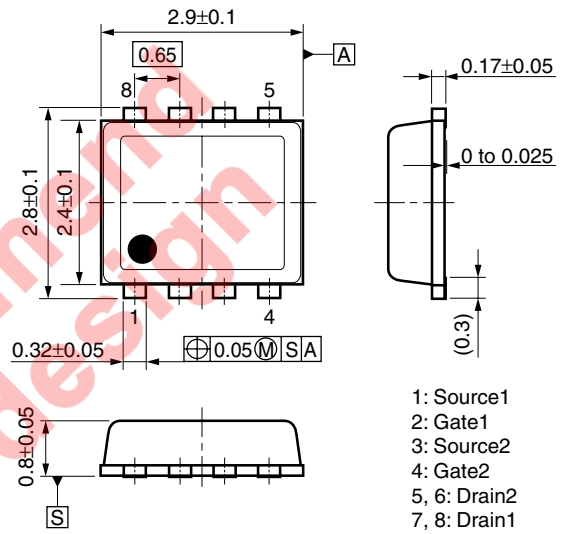
The  $\mu$ PA2550 is dual P-channel MOSFETs designed for power management applications of portable equipments, such as load switch.

Dual P-channel MOSFETs are assembled in one package, to contribute minimize the equipments.

### FEATURES

- 1.8 V drive available
- Low on-state resistance
  - $R_{DS(on)1} = 40 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -2.5 \text{ A)}$
  - $R_{DS(on)2} = 60 \text{ m}\Omega \text{ MAX. (} V_{GS} = -2.5 \text{ V, } I_D = -2.5 \text{ A)}$
  - $R_{DS(on)3} = 93 \text{ m}\Omega \text{ MAX. (} V_{GS} = -1.8 \text{ V, } I_D = -2.5 \text{ A)}$
- Built-in gate protection diode
- Small and surface mount package (8-pin VSO (2429))

### PACKAGE DRAWING (Unit: mm)



### ORDERING INFORMATION

| PART NUMBER                           | LEAD PLATING | PACKING              | PACKAGE          |
|---------------------------------------|--------------|----------------------|------------------|
| $\mu$ PA2550T1H-T1-AT <sup>Note</sup> | Pure Sn      | 8 mm embossed taping | 8-pin VSO (2429) |
| $\mu$ PA2550T1H-T2-AT <sup>Note</sup> |              | 3000 p/reel          |                  |

**Note** Pb-free (This product does not contain Pb in the external electrode and other parts.)

**Marking:** 2550

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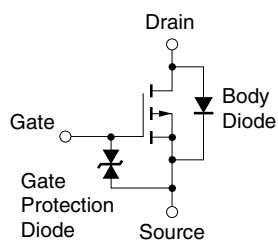
**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)**

|   |                       |             |    |
|---|-----------------------|-------------|----|
| Drain to Source Voltage (V <sub>GS</sub> = 0 V)         | V <sub>DSS</sub>      | -12         | V  |
| Gate to Source Voltage (V <sub>DS</sub> = 0 V)          | V <sub>GSS</sub>      | ±8          | V  |
| Drain Current (DC)                                      | I <sub>D(DC)</sub>    | ±5.0        | A  |
| Drain Current (pulse) <sup>Note1</sup>                  | I <sub>D(pulse)</sub> | ±20         | A  |
| Total Power Dissipation (1 unit, 5 s) <sup>Note2</sup>  | P <sub>T1</sub>       | 1.5         | W  |
| Total Power Dissipation (2 units, 5 s) <sup>Note2</sup> | P <sub>T2</sub>       | 2.2         | W  |
| Channel Temperature                                     | T <sub>ch</sub>       | 150         | °C |
| Storage Temperature                                     | T <sub>stg</sub>      | -55 to +150 | °C |

**Notes 1.** PW ≤ 10 μs, Duty Cycle ≤ 1%

**2.** Mounted on FR-4 board of 25.4 mm x 25.4 mm x 0.8 mm

**EQUIVALENT CIRCUIT (1/2)**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

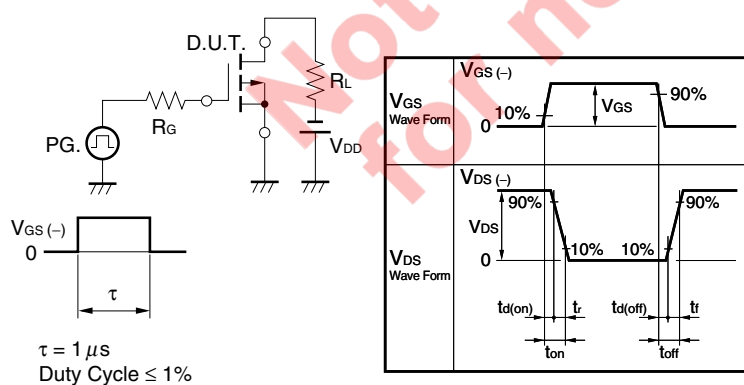
**Caution** This product is electrostatic-sensitive device due to low ESD capability and should be handled with caution for electrostatic discharge.

ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

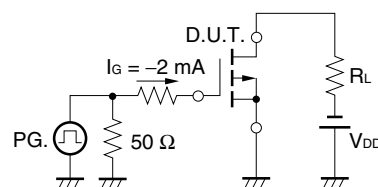
| CHARACTERISTICS                                 | SYMBOL               | TEST CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|---|----------------------|--|------|------|------|------|
| Zero Gate Voltage Drain Current                 | I <sub>DSS</sub>     | V <sub>DS</sub> = -12 V, V <sub>GS</sub> = 0 V                           |      |      | -1   | μA   |
| Gate Leakage Current                            | I <sub>GSS</sub>     | V <sub>GS</sub> = ±8 V, V <sub>DS</sub> = 0 V                            |      |      | ±10  | μA   |
| Gate to Source Cut-off Voltage                  | V <sub>GS(off)</sub> | V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1 mA                          | -0.4 | -0.7 | -1.0 | V    |
| Forward Transfer Admittance <b>Note</b>         | y <sub>fs</sub>      | V <sub>DS</sub> = -10 V, I <sub>D</sub> = -2.5 A                         | 3.5  |      |      | S    |
| Drain to Source On-state Resistance <b>Note</b> | R <sub>DS(on)1</sub> | V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -2.5 A                        |      | 29   | 40   | mΩ   |
|   | R <sub>DS(on)2</sub> | V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -2.5 A                        |      | 37   | 60   | mΩ   |
|   | R <sub>DS(on)3</sub> | V <sub>GS</sub> = -1.8 V, I <sub>D</sub> = -2.5 A                        |      | 53   | 93   | mΩ   |
| Input Capacitance                               | C <sub>iss</sub>     | V <sub>DS</sub> = -10 V,   |      | 930  |      | pF   |
| Output Capacitance                              | C <sub>oss</sub>     | V <sub>GS</sub> = 0 V,   |      | 200  |      | pF   |
| Reverse Transfer Capacitance                    | C <sub>rss</sub>     | f = 1.0 MHz  |      | 170  |      | pF   |
| Turn-on Delay Time                              | t <sub>d(on)</sub>   | V <sub>DD</sub> = -6 V, I <sub>D</sub> = -2.5 A,                         |      | 11   |      | ns   |
| Rise Time                                       | t <sub>r</sub>       | V <sub>GS</sub> = -4 V,  |      | 3.3  |      | ns   |
| Turn-off Delay Time                             | t <sub>d(off)</sub>  | R <sub>G</sub> = 6 Ω   |      | 70   |      | ns   |
| Fall Time                                       | t <sub>f</sub>       |  |      | 46   |      | ns   |
| Total Gate Charge                               | Q <sub>G</sub>       | V <sub>DD</sub> = -6 V, V <sub>GS</sub> = -4 V,<br>I <sub>D</sub> = -5 A |      | 8.7  |      | nC   |
| Body Diode Forward Voltage <b>Note</b>          | V <sub>F(S-D)</sub>  | I <sub>F</sub> = -5 A, V <sub>GS</sub> = 0 V                             |      | 0.9  |      | V    |

**Note** Pulsed

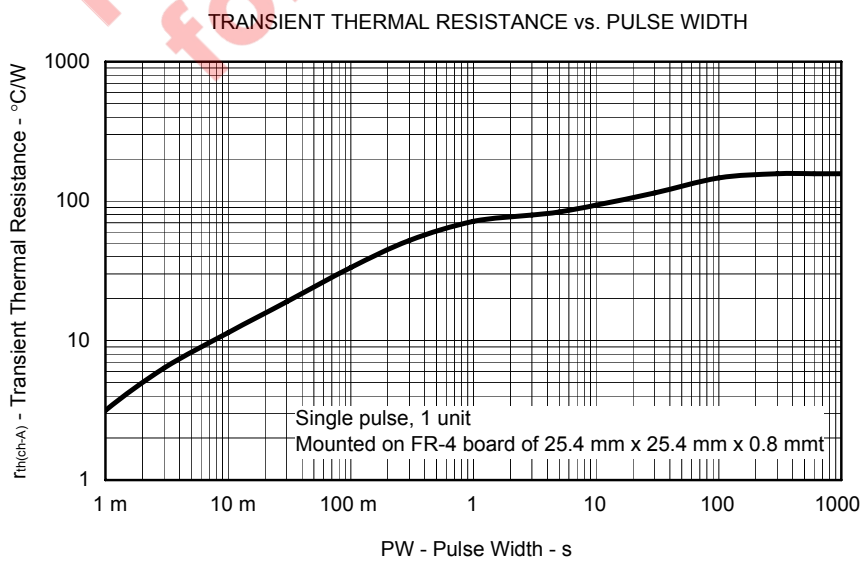
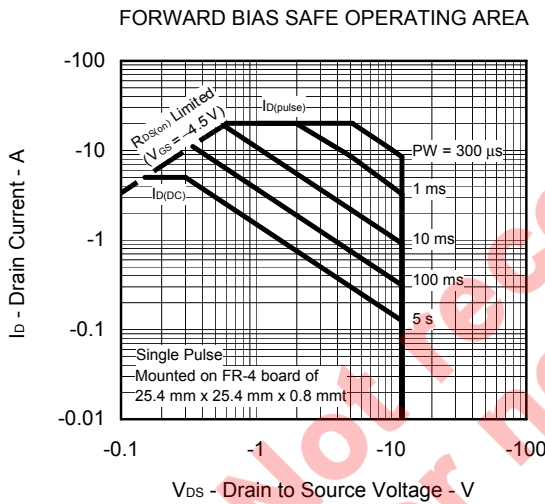
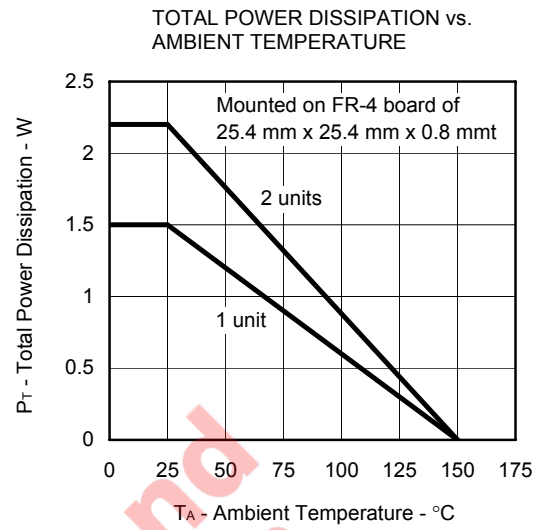
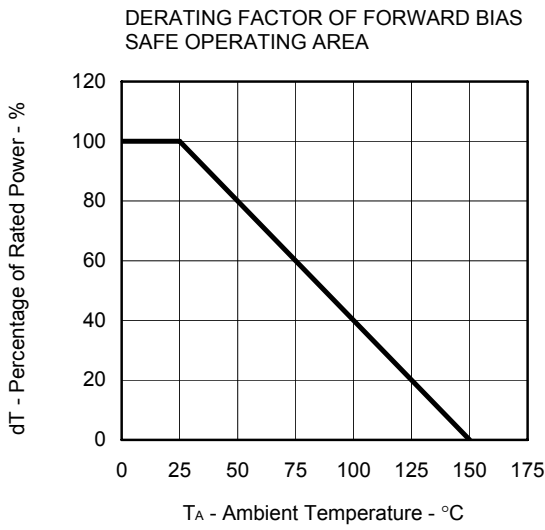
TEST CIRCUIT 1 SWITCHING TIME



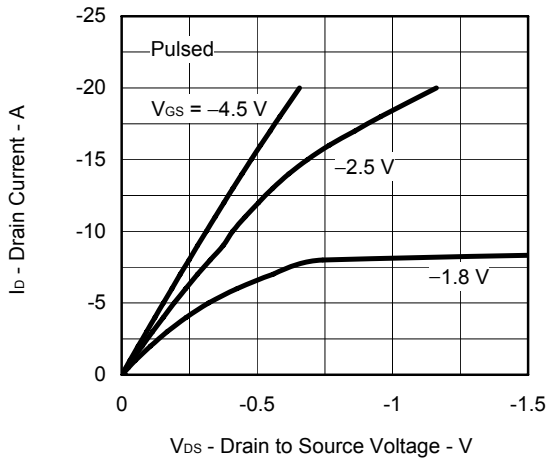
TEST CIRCUIT 2 GATE CHARGE



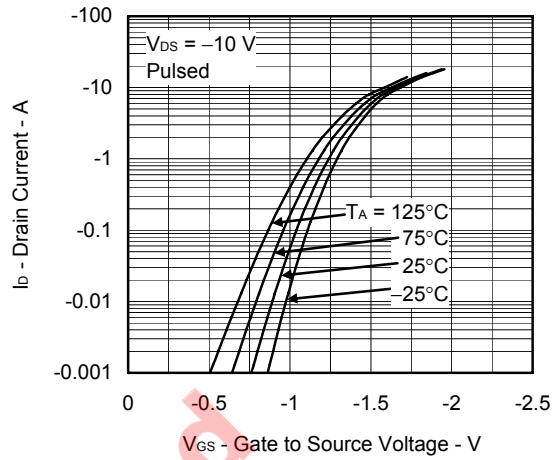
TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)



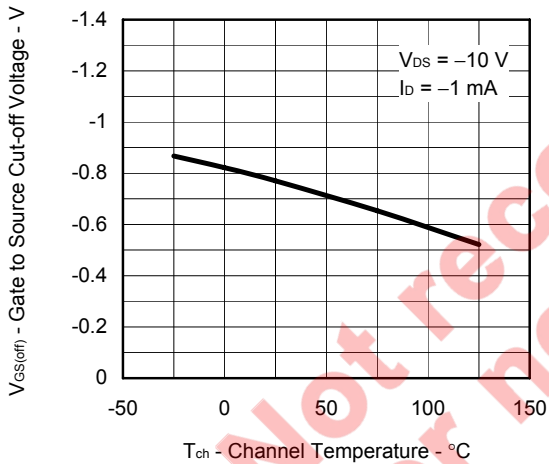
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



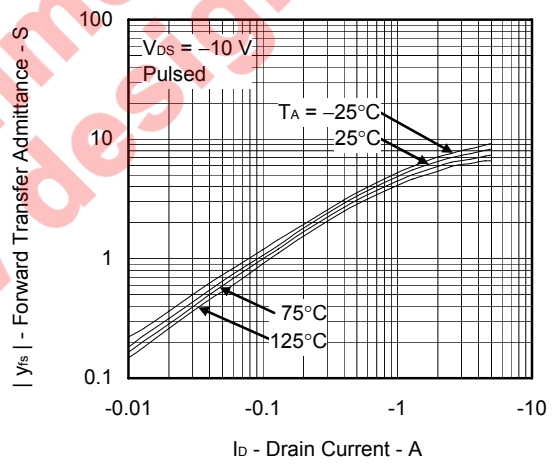
FORWARD TRANSFER CHARACTERISTICS



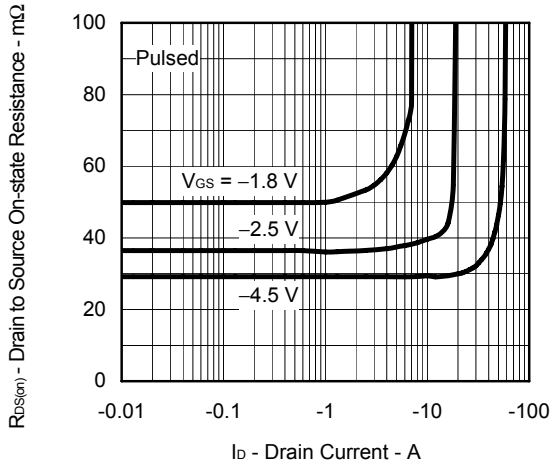
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



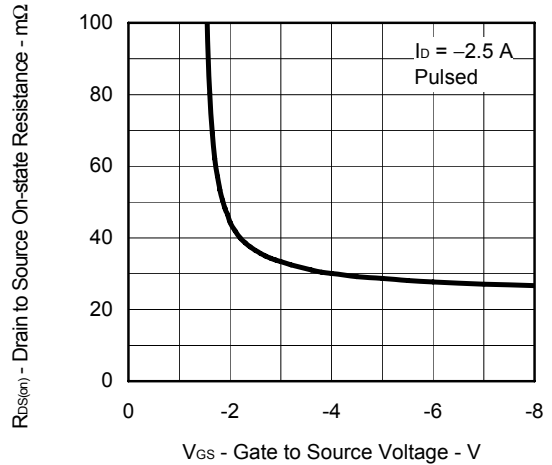
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



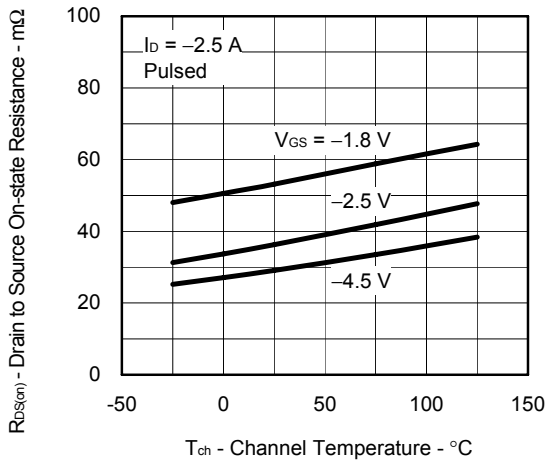
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



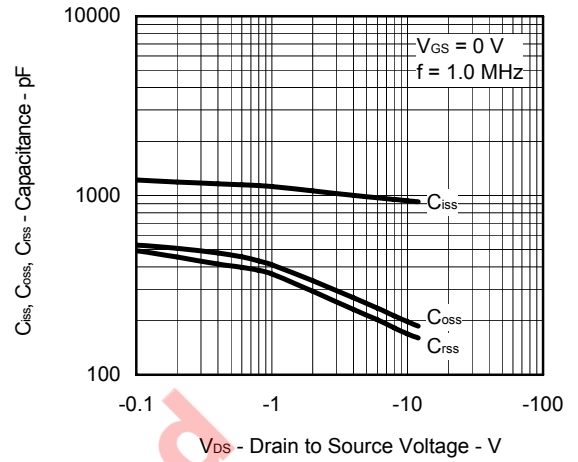
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



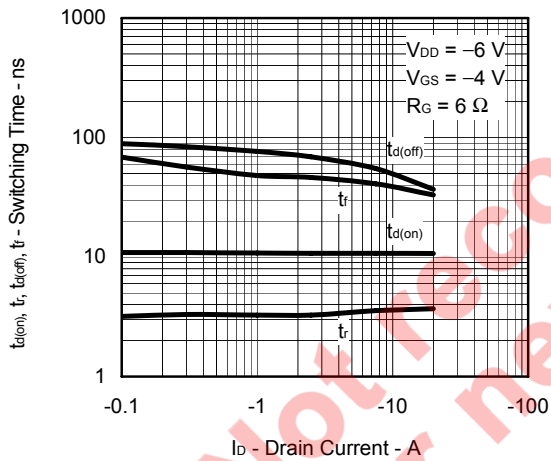
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



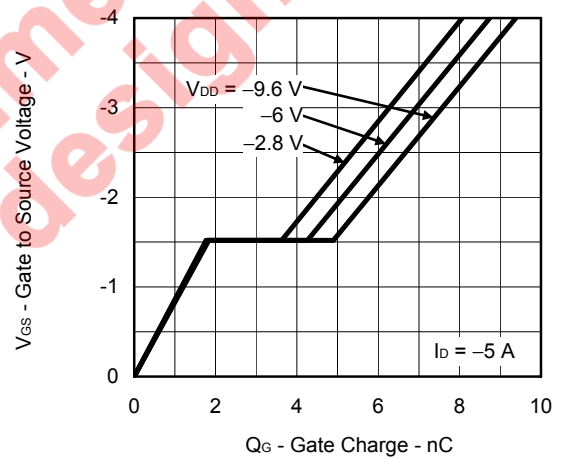
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



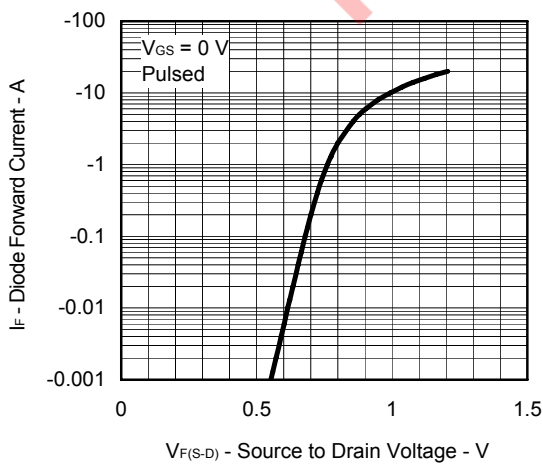
SWITCHING CHARACTERISTICS



DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE





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